NSN 5961-01-049-3582

Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
0.615 inches
Terminal Length:
0.500 inches
Overall Height:
0.190 inches
Overall Width:
0.420 inches
Function For Which Designed:
Rectifier
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal and unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
300.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
4.00 amperes source cutoff current preset
Power Rating Per Characteristic:
0.5 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
110.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

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